

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









200mW, Low VF SMD Schottky Barrier Diode

FEATURES

- · Designed for mounting on small surface
- Low Capacitance
- Low forward voltage drop
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Adapters
- For switching power supply
- Low stored charge
- Inverter

MECHANICAL DATA

- Case: SOT-23
- Molding compound: UL flammability classification rating 94V-0
- Moisture sensitivity level: level 1, per J-STD-020
- Packing code with suffix "G" means green compound (halogen-free)
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Weight: 8 mg (approximately)

KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
I _{F(AV)}	200	mA		
V_{RRM}	40	V		
I _{FSM}	0.6	Α		
V _F at I _F =40mA	1	V		
T _J Max.	125	°C		
Package	SOT-23			





ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)						
PARAMETER	SYMBOL	BAS40	BAS40- 04	BAS40- 05	BAS40- 06	UNIT
Marking code on the device		43	44	45	46	
Repetitive peak reverse voltage	V_{RRM}	40				V
Forward current	I _{F(AV)}	200				mA
Non-repetitive peak forward surge current @t = 8.3ms	I _{FSM}	0.6			Α	
Junction temperature range	T _J	-65 to +125			°C	
Storage temperature range	T _{STG}	-65 to +125			°C	

1



THERMAL PERFORMANCE					
PARAMETER	SYMBOL	LIMIT	UNIT		
Junction-to-ambient thermal resistance	$R_{\Theta JA}$	357	°C/W		

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS SYMBOL		MIN	MAX	UNIT	
 (1)	I _F = 1mA, T _J = 25°C			0.38	V	
Forward voltage per diode (1)	I _F = 40mA, T _J = 25°C	V_{F}	-	1.00		
Reverse current @ rated V _R per diode ⁽²⁾	nt @ rated V_R per $V_R=30V T_J=25$ °C		-	0.2	μΑ	
Reverse Breakdown Voltage I _R =10µA		$V_{(BR)}$	40	-	V	
Junction capacitance	1 MHz, V _R =1V	C _J	-	5.0	pF	
Reverse Recovery Time	$I_F=I_R=10$ mA, $R_L=100$ Ω , $I_{RR}=1$ mA	t _{rr}	-	5.0	ns	

Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms

ORDERING INFORMATION					
PART NO.	PACKING CODE	PACKING CODE SUFFIX(*)	PACKAGE	PACKING	
BAS40-XX (Note 1)	RF	G	SOT-23	3K / 7" Reel	

Notes:

1. "XX" is Device code from "04" to "06".

^{*:} optional available

EXAMPLE				
EXAMPLE P/N	PART NO.	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
BAS40-04 RFG	BAS40-04	RF	G	Green compound



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig. 1 Power Derating Curve

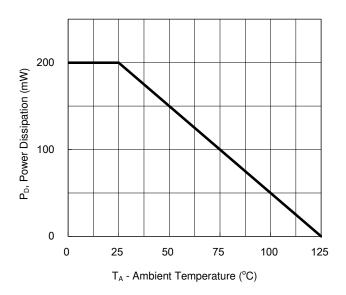


Fig.2 Maximum Non-Repetitve Peak Forward Surge Current Per Leg

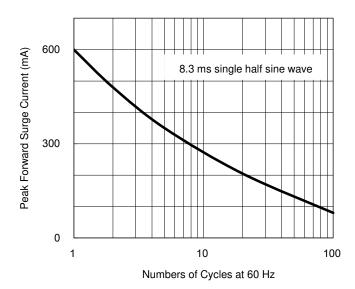


Fig.3 Typical Forward Characteristics

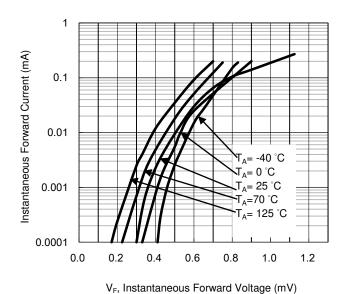
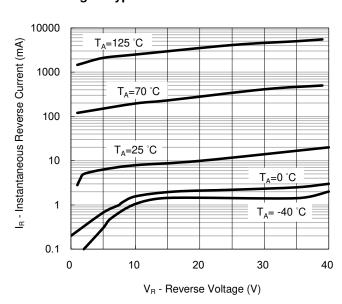


Fig.4 Typical Reverse Characteristics





CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig. 5 Typical Total Capacitance VS.

Reverse Voltage

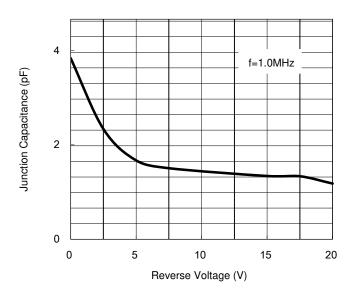
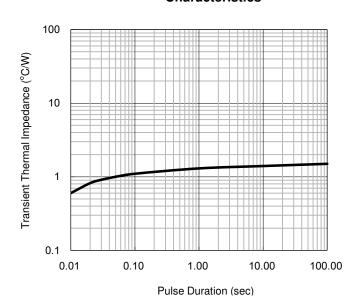


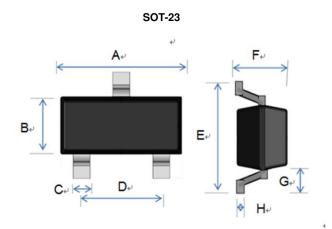
Fig.6 Typical Transient Thermal Characteristics





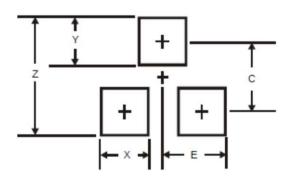


PACKAGE OUTLINE DIMENSION



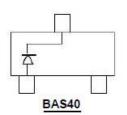
DIM	Unit(mm)		Unit(inch)
DIM.	Min	Max	Min	Max
Α	2.70	3.10	0.106	0.122
В	1.10	1.50	0.043	0.059
С	0.30	0.51	0.012	0.020
D	1.78	2.04	0.070	0.080
E	2.10	2.64	0.083	0.104
F	0.89	1.30	0.035	0.051
G	0.55 REF		0.022	REF
Н	0.10 REF		0.004	REF

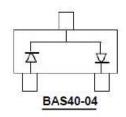
SUGGEST PAD LAYOUT

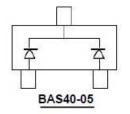


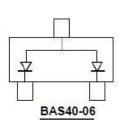
DIM.	Unit(mm)	Unit(inch)		
ТҮР		TYP		
Z	2.8	0.11		
Х	0.7	0.03		
Y	0.9	0.04		
С	1.9	0.07		
E	1.0	0.04		

PIN CONFIGURATION









Taiwan Semiconductor

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.